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**SCULLY, SCOTT, MURPHY  
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JUL 26 2002

TECHNOLOGY CENTER 2800

<b>To:</b>	Examiner Cuong Q. Nguyen	<b>From:</b>	Leslie S. Szivos
<b>Fax:</b>	703-872-9319	<b>Pages:</b>	13 Including cover
<b>Phone:</b>		<b>Date:</b>	7/26/2002
<b>Re:</b>	<b>U.S. Patent Appln. No. 09/516,615</b>		
	IBM Ref: BUR919990190US1		
	SSMP Docket: 13020		
	For: METHOD OF FABRICATING A		
	POLYSILICON CAPACITOR UTILIZING FET AND		
	BIPOLAR BASE POLYSILICON LAYERS		

## FINAL REJECTION

• **Comments:**

1. Amendment Transmittal Letter (in duplicate)
2. Response under 37 C.F.R. §1.116
3. Authorization to Charge Deposit Account
4. Certificate of Transmission by Facsimile dated July 26, 2002

Applicants: Douglas D. Coolbaugh, et al.  
 Serial No. 09/516,615  
 Filed: March 1, 2000  
 For: METHOD OF FABRICATING A POLYSILICON CAPACITOR UTILIZING FET AND  
 BIPOLAR BASE POLYSILICON LAYERS  
 Docket: BUR919990190US1 (13020)  
 Dated: July 26, 2002

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**AMENDMENT TRANSMITTAL LETTER (Large Entity)**

Applicant(s): Douglas D. Coolbaugh, et al.

Docket No.

BUR919990190US1 (13020)

Serial No.  
09/516,615Filing Date  
March 1, 2000Examiner  
Cuong Q. NguyenGroup Art Unit  
2811**Invention: METHOD OF FABRICATING A POLYSILICON CAPACITOR UTILIZING FET  
AND BIPOLAR BASE POLYSILICON LAYERS****TO THE ASSISTANT COMMISSIONER FOR PATENTS:**

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

**CLAIMS AS AMENDED**

	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER EXTRA CLAIMS PRESENT	RATE	ADDITIONAL FEE
TOTAL CLAIMS	7 -	20 =	0	x \$18.00	\$0.00
INDEP. CLAIMS	4 -	3 =	1	x \$84.00	\$84.00
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					\$0.00
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT					\$84.00

- No additional fee is required for amendment.
- Please charge Deposit Account No. \_\_\_\_\_ in the amount of \_\_\_\_\_  
A duplicate copy of this sheet is enclosed.
- A check in the amount of \_\_\_\_\_ to cover the filing fee is enclosed.
- The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 09-0456/IBM  
A duplicate copy of this sheet is enclosed.
- Any additional filing fees required under 37 C.F.R. 1.16.
- Any patent application processing fees under 37 CFR 1.17.

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Signature

Dated: July 26, 2002

JUL 26 2002

Leslie S. Szivos  
Registration No. 39,394

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I certify that this document and fee is being deposited on _____ with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Assistant Commissioner for Patents, Washington, D.C. 20231.	
Signature of Person Mailing Correspondence	
Typed or Printed Name of Person Mailing Correspondence	

LSS:tt:gmj  
cc:

**CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)**Applicant(s): **D uglas D. Coolbaugh, et al.**

Docket No.

**BUR919990190US1 (13020)**Serial No.  
**09/516,615**Filing Date  
**March 1, 2000**Examiner  
**Cuong Q. Nguyen**Group Art Unit  
**2811**

**Invention:** **METHOD OF FABRICATING A POLYSILICON CAPACITOR UTILIZING FET AND  
BIPOLAR BASE POLYSILICON LAYERS**

I hereby certify that this Response under 37 C.F.R. §1.116  
(Identify type of correspondence)

is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. (703) 872-9319)

on July 26, 2002  
(Date)

Gina Johnston(Typed or Printed Name of Person Signing Certificate)Gina Johnston  
(Signature)

**Note: Each paper must have its own certificate of mailing.**

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